

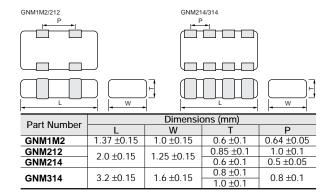
Capacitor Arrays

■ Features

- 1. High density mounting due to mounting space saving
- 2. Mounting cost saving

■ Applications

General electronic equipment



Temperature Compensating Type

Part Number	rt Number GNM31				
LxW	3.	2x1.6			
тс	C0G (5C)				
Rated Volt.	100 (2A)	50 (1H)			
Capacitance (Capacitance pa	rt numbering code) and T (mm) Dimension (T Dime	ension part numbering code)			
10pF(100)	0.8(4)	0.8(4)			
11pF(110)	0.8(4)	0.8(4)			
12pF(120)	0.8(4)	0.8(4)			
13pF(130)	0.8(4)	0.8(4)			
15pF(150)	0.8(4)	0.8(4)			
16pF(160)	0.8(4)	0.8(4)			
18pF(180)	0.8(4)	0.8(4)			
20pF(200)	0.8(4)	0.8(4)			
22pF(220)	0.8(4)	0.8(4)			
24pF(240)	0.8(4)	0.8(4)			
27pF(270)	0.8(4)	0.8(4)			
30pF(300)	0.8(4)	0.8(4)			
33pF(330)	0.8(4)	0.8(4)			
36pF(360)	0.8(4)	0.8(4)			
39pF(390)	0.8(4)	0.8(4)			
43pF(430)	0.8(4)	0.8(4)			
47pF(470)	0.8(4)	0.8(4)			
51pF(510)	0.8(4)	0.8(4)			
56pF(560)	0.8(4)	0.8(4)			
62pF(620)	0.8(4)	0.8(4)			
68pF(680)	0.8(4)	0.8(4)			
75pF(750)	0.8(4)	0.8(4)			
82pF(820)	0.8(4)	0.8(4)			
91pF(910)	0.8(4)	0.8(4)			
100pF(101)	0.8(4)	0.8(4)			
110pF(111)	0.8(4)	0.8(4)			
120pF(121)	0.8(4)	0.8(4)			
130pF(131)	0.8(4)	0.8(4)			
150pF(151)	0.8(4)	0.8(4)			
160pF(161)		0.8(4)			
180pF(181)		0.8(4)			

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Part Number	GNM31						
LxW	3.2)	x1.6					
TC	C0G (5C)						
Rated Volt.	100 (2A)	50 (1H)					
Capacitance (Capac	itance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)					
200pF(201)		0.8(4)					
220pF(221)		0.8(4)					
240pF(241)		0.8(4)					
270pF(271)		0.8(4)					
300pF(301)		0.8(4)					
330pF(331)		0.8(4)					
360pF(361)		0.8(4)					

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM1 Series

Part Number	GNM1M					
LxW	1.37x1.00					
тс	X7R (R7)					
Rated Volt.	16 (1C)	10 (1A)				
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
22000pF(223)	0.6(2)					
47000pF(473)	0.6(2)					
0.10μF(104)		0.6(2)				

The part numbering code is shown in each (). The (2) code in T(mm) means number of elements (two). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM2 Series

Part Number	GNM21
LxW	2.0x1.25
тс	X7R (R7)
Rated Volt.	50 (1H)
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)
1000pF(102)	0.6(4)
10000pF(103)	0.6(4)

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM3 Series

Part Number	GNM31							
LxW		3.2x1.6						
тс	X7R (R7)					Y5V (F5)		
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	16 (1C)	
Capacitance (Ca	Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)							
220pF(221)	0.8(4)							

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Part Number				GNM31				
LxW				3.2x1.6				
тс	X7R (R7)				Y5V (F5)			
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	16 (1C)	
Capacitance (Capa	acitance part nu	mbering code) and	T (mm) Dimension	(T Dimension part	numbering code)			
270pF(271)	0.8(4)							
330pF(331)	0.8(4)							
390pF(391)	0.8(4)	0.8(4)						
470pF(471)	0.8(4)	0.8(4)						
560pF(561)	0.8(4)	0.8(4)						
680pF(681)	0.8(4)	0.8(4)						
820pF(821)	0.8(4)	0.8(4)						
1000pF(102)	0.8(4)	0.8(4)						
1200pF(122)	0.8(4)	0.8(4)						
1500pF(152)	0.8(4)	0.8(4)						
1800pF(182)	0.8(4)	0.8(4)						
2200pF(222)	0.8(4)	0.8(4)			0.8(4)			
2700pF(272)	0.8(4)	0.8(4)						
3300pF(332)	0.8(4)	0.8(4)			0.8(4)			
3900pF(392)	0.8(4)	0.8(4)						
4700pF(472)	0.8(4)	0.8(4)			0.8(4)			
5600pF(562)		0.8(4)						
6800pF(682)		0.8(4)						
8200pF(822)		0.8(4)						
10000pF(103)		0.8(4)						
12000pF(123)		0.8(4)						
15000pF(153)		0.8(4)						
18000pF(183)			0.8(4)					
22000pF(223)				0.8(4)		0.8(4)		
27000pF(273)				0.8(4)				
33000pF(333)				0.8(4)		0.8(4)		
39000pF(393)				0.8(4)				
47000pF(473)				1.0(4)		0.8(4)		
68000pF(683)				1.0(4)			0.8(4)	
0.10μF(104)				1.0(4)			0.8(4)	
0.15μF(154)							0.8(4)	

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four).

Dimensions are shown in mm and Rated Voltage in Vdc.

Specifications and Test Methods

				Specifications					
No.	Ite	em	Temperature Compensating Type	High Dielectric Type		Test Method			
1	Operating Temperatu	ıre Range	5C : −55°C to +125°C	R7 : −55°C to +125°C F5 : −30°C to +85°C					
2	Rated Vo	ltage	See the previous pages.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{p,p} or V ^{o,p} , whichever is larger, should be maintained within the rated voltage range.				
3	Appearance		No defects or abnormaliti	es	Visual inspection				
4	Dimensio	n	Within the specified dime	nsions	Using calipers				
5	Dielectric	Strength	No defects or abnormaliti	es	No failure should be o (5C) or 250% of the ra the terminations for 1 charge current is less	ated voltage (R7, F5 to 5 seconds, provid) is applie	ed between	
6	Insulation I	Resistance	More than 10,000M Ω or (Whichever is smaller)	500Ω • F	The insulation resistar age not exceeding the and within 2 minutes of	rated voltage at 25			
7	Capacita	nce	Within the specified tolera	ance	The capacitance/Q/D.		red at 25	℃ at the fre-	
			30pF min. : Q≥1000 30pF max. : Q≥400+20C		quency and voltage sh				
8	•	Dissipation Factor 30pF max. : Q≥400+20C C : Nominal Capacitance		R7 0.025 max. 0.035 max. 0.035 max.	Item Char	5C 1±0.1MHz		7, F5 1.1kHz	
	(D.F.)			F5 0.05 max. 0.07 max	Voltage	0.5 to 5Vr.m.s.		2Vr.m.s.	
9	Capacitance Temperature Characteristics	Capacitance Change Temperature Coefficient Capacitance Drift	(pF) Within the specified tolerance (Table A) Within the specified tolerance (Table A) Within ±0.2% or ±0.05 pF (Whichever is larger)	Char. Temp. Range Reference Range Cap. Change Change R7 −55 to +125℃ 25℃ Within±15% Within±22%	The capacitance chan each specified temper (1) Temperature Composition (1) Temperature Composition (2) The temperature capacitance measured When cycling the temperature of capacitance of the temperature of the change as Table A. The capacitance of differences between values in steps 1, 3. Step 1 2 3 4 5 (2) High Dielectric Composition (2) The ranges of caparabove 25°C value of caparabove 25°C valu	ge should be meas ature stage. been sating Type befficient is determinated in step 3 as a remperature sequent acitance should be a mperature coefficient. Temperature coefficient is calculated by don the maximum and a and 5 by the capactor and 5 for 50 R7 25±3 (for 50 R7 25±125±3 (for 5	ured after med using eference. tially from within the nt and cal ividing the minimum itance val ture (°C) :2 :2 :7), -30±3 :2 :2 mpared we eranges s	the step1 specified pacitance en measured lue in step 3. (for F5)	
10	Adhesive Strenger of Termination		No removal of the terminations or other defect should occur. By Solder resist Copper foil		Solder the capacitor to the test jig (glass epoxy board) shown Fig. 1 using a eutectic solder. Then apply 5N force in parallel with the test jig for 10±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. Type a b c d GNM1M 0.5 - 0.32 0.32 GNM21 0.4 1.6 0.25 0.5 GNM21 0.8 2.5 0.4 0.8 (in mm) Fig. 1				

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Specifications and Test Methods

Ontinued from the preceding page.

			Specifications						
No.	Ite	em	Temperature Compensating Type	High Dielectric Type	Test Method Solder the capacitor to the test jig (glass epoxy board) in the				
		Appearance	No defects or abnormaliti	es	1				
		Capacitance	Within the specified tolera	ance	same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion				
11	Vibration Resistance	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. —	having a total amplitude of 1 uniformly between the approximate frequency range, from 1 should be traversed in approximate.	.5mm, the frequency being varie eximate limits of 10 and 55Hz. 0 to 55Hz and return to 10Hz, eximately 1 minute. This motion and of 2 hours in each of 3 mutual al of 6 hours).			
			No cracking or marking d	efects should occur.		•	d) shown		
			•GNM□□4	•GNM□□2	in Fig. 2 using a eutectic solder. Then apply a force tion shown in Fig. 3 for 5±1 sec. The soldering she either with an iron or using the reflow method and conducted with care so that the soldering is uniform defects such as heat shock.		ld be done ould be		
12	Deflection	n	5.0 100 5.0 100 Type a GNM1M 2.0±(GNM21 2.0±(GNM31 2.5±(0.05 0.5±0.05 0.32±0.05 0.32±0.05 0.05 0.7±0.05 0.3±0.05 0.2±0.05	20 50 Pressurizing speed : 1.0mm/sec. Pressurize R230 Flexure : ≦1 Capacitance meter 45 45 (in mm)				
				(in mm) Fig. 2			(GNM31)		
13	Solderabi Terminati	•	75% of the terminations a continuously.	are to be soldered evenly and	Immerse the capacitor in a srosin (JIS-K-5902) (25% rosi 80 to 120℃ for 10 to 30 seco eutectic solder solution for 2:	n in weight proportion). Inds. After preheating, in	Preheat at nmerse in		
			The measured and obser specifications in the follow	rved characteristics should satisfy the wing table.					
		Appearance	No marking defects		Preheat the capacitor at 120	to 150℃ for 1 minute. Ir	C for 1 minute. Immerse the		
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	capacitor in a eutectic solder seconds. Let sit at room tem	perature for 24±2 hours	(tempera-		
14	Resistance to Soldering Heat	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	ture compensating type) or 4 type), then measure. • Initial measurement for high Perform a heat treatment at let sit for 48±4 hours at room	n dielectric constant type 150 [±] 0, ℃ for one hour	e and then		
		I.R.		500Ω • F (Whichever is smaller)	measurement.	rtemperature. r enomi t	ile ililiai		
		Dielectric Strength	No failure	,					
			The measured and obser specifications in the follow	rved characteristics should satisfy the wing table.	y the Fix the capacitor to the supporting jig in the under the same conditions as (10). Perform				
		Appearance	No marking defects		according to the four heat tre		•		
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	table. Let sit for 24±2 hours or 48±4 hours (high dielectric ture, then measure				
15	Temperature Cycle	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. —	Step 1 Temp. (°C) Min. Operating Temp. ⁺ ° ₃ Time (min.) 30±3	2 3 Room Max. Operating Temp. +3 2 to 3 30±3	Room Temp. 2 to 3		
			(pF)		Initial measurement for high				
		I.R.	More than 10,000MΩ or	500Ω • F (Whichever is smaller)	Perform a heat treatment at	150 ^{±o} ₀ ℃ for one hour	and then		
		Dielectric Strength	No failure		let sit for 48±4 hours at room measurement.	temperature. Perform t	he initial		

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Specifications and Test Methods

	Continued from the preceding page.										
				Specifications							
No.	Ite	em	Temperature Compensating Type	High Dielectric Type	Test Method						
			The measured and obserspecifications in the follow	rved characteristics should satisfy the wing table.							
		Appearance	No marking defects								
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Let the capacitor sit at 40±2°C and 90 to 95% humidity for						
16	Humidity Steady State	Q/D.F.	30pF and over: Q≥350 10pF and over, 30pF and below:	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	South the capacitor at at 40±2 c and so to 50 % naminary for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.						
		I.R.	More than 1,000MΩ or 5	0Ω • F (Whichever is smaller)							
		Dielectric Strength	No failure								
		The measured and observed characteristics should satisfy the specifications in the following table.									
		Appearance	No marking defects								
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply the rated voltage at 40±2°C and 90 to 95% humidity for						
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.						
		I.R.	More than 500MΩ or 250	2 • F (Whichever is smaller)							
		Dielectric Strength	No failure								
		The measured and observed characteristics should satisfy the specifications in the following table.									
		Appearance	No marking defects								
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply 200% of the rated voltage for 1000±12 hours at the						
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.						
		I.R.	More than 1,000M Ω or 5	0Ω • F (Whichever is smaller)							
		Dielectric Strength	No failure								

Table A

			Capacitance Change from 25℃ (%)					
Char.	Nominal Values (ppm/℃) Note 1	-55		-30		-10		
	(ppiii/ c) Note i	Max.	Min.	Max.	Min.	Max.	Min.	
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11	

Note 1 : Nominal values denote the temperature coefficient within a range of 25°C to 125°C.